

Solid State Relay OCMOS FET

# PS7122-1A,-2A,PS7122L-1A,-2A

### 6, 8-PIN DIP, 200 V BREAK DOWN VOLTAGE 1-ch, 2-ch Optical Coupled MOS FET

#### **DESCRIPTION**

The PS7122-1A, -2A and PS7122L-1A, -2A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs on the output side.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7122L-1A, -2A have a surface mount type lead.

#### \* FEATURES

- 1 channel type (1 a output) or 2 channel type (1 a + 1 a output)
- Low LED operating current (IF = 2 mA)
- · Designed for AC/DC switching line changer
- Small package (6, 8-pin DIP)
- · Low offset voltage
- PS7122L-1A, -2A: Surface mount type
- UL approved: File No. E72422 (S)
- BSI approved: No. 8245/8246
- · CSA approved: No. CA 101391

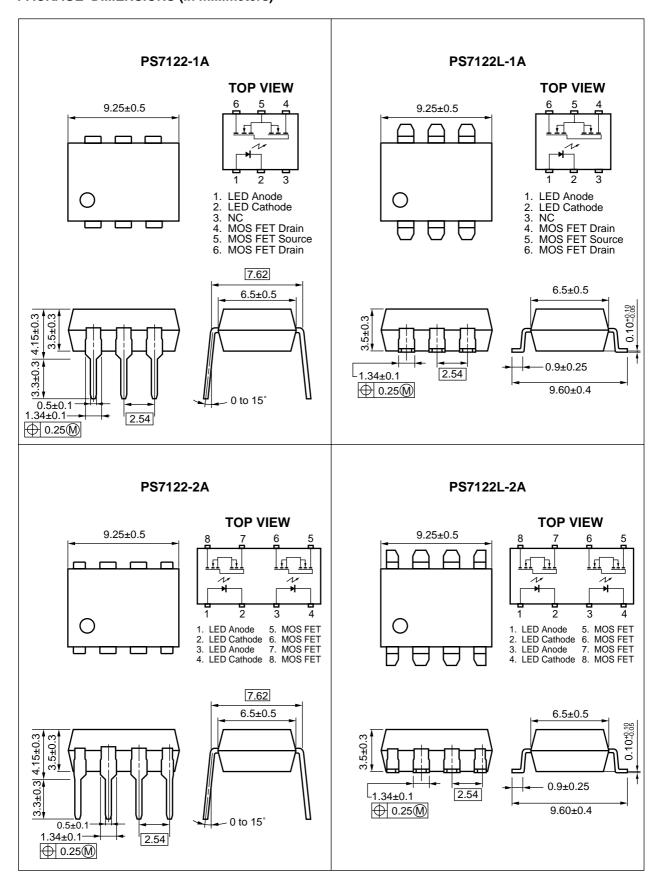
#### **APPLICATIONS**

- · Exchange equipment
- · Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

#### **PACKAGE DIMENSIONS (in millimeters)**



#### **★** ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number*1
PS7122-1A	6-pin DIP	Magazine case 50 pcs	PS7122-1A
PS7122L-1A			PS7122L-1A
PS7122L-1A-E3		Embossed Tape 1 000 pcs/reel	
PS7122L-1A-E4			
PS7122-2A	8-pin DIP	Magazine case 50 pcs	PS7122-2A
PS7122L-2A			PS7122L-2A
PS7122L-2A-E3		Embossed Tape 1 000 pcs/reel	
PS7122L-2A-E4			

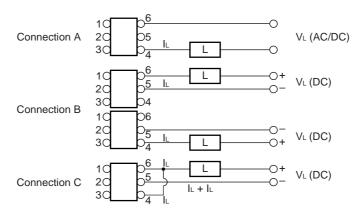
<sup>\*1</sup> For the application of the Safety Standard, following part number should be used.

#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter				Rati		
			Symbol	PS7122-1A, PS7122L-1A	PS7122-2A, PS7122L-2A	Unit
Diode	riode Forward Current (DC)  Reverse Voltage  Power Dissipation		<b>I</b> F	50		mA
			VR	5.0		V
			Po	50		mW/ch
	Peak Forward Current <sup>*1</sup>		IFP	1		Α
MOS FET	FET Break Down Voltage		VL	200		V
	Continuous	Connection A	l <sub>L</sub>	200		mA
	Load Current <sup>*2</sup>	Connection B		350	-	
		Connection C		500	-	
	Pulse Load Current <sup>*3</sup> (AC/DC Connection)		Ігь	400		mA
	Power Dissipation		Po	560	375	mW/ch
Isolation Voltage '4			BV	1 500		Vr.m.s.
Total Power Dissipation			Рт	610	850	mW
Operating Ambient Temperature			TA	-40 to +80		°C
Storage Temperature			T <sub>stg</sub>	-40 to +100		°C

<sup>\*1</sup> PW = 100  $\mu$ s, Duty Cycle = 1 %

<sup>\*2</sup> Conditions: IF  $\geq$  2 mA. The following types of load connections are available.



<sup>\*3</sup> PW = 100 ms, 1 shot

<sup>\*4</sup> AC voltage for 1 minute at  $T_A = 25$  °C, RH = 60 % between input and output

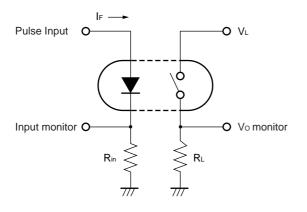
#### RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

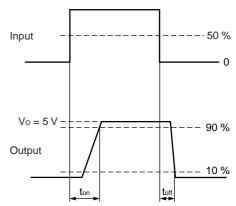
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

#### **★** ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage		IF = 10 mA		1.2	1.4	V
	Reverse Current	lR	V <sub>R</sub> = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current   I <sub>Loff</sub>   V <sub>D</sub> = 200 V			0.03	1.0	μΑ	
	Output Capacitance	Cout	V <sub>D</sub> = 0 V, f = 1 MHz		165		pF/ch
Coupled	LED On-state Current	<b>I</b> Fon	IL = 200 mA			2.0	mA
	On-state Resistance	Ron1	IF = 10 mA, IL = 10 mA		3.0	5.0	Ω
		Ron2	$I_F = 10 \text{ mA}, I_L = 200 \text{ mA}, t \le 10 \text{ ms}$				
	Turn-on Time <sup>*1</sup>	ton	I <sub>F</sub> = 10 mA, V <sub>O</sub> = 5 V, PW ≥ 10 ms		0.6	2.0	ms
	Turn-off Time <sup>*1</sup>	toff			0.06	0.2	
	Isolation Resistance	R <sub>I-O</sub>	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1 MHz		1.1		pF/ch

#### \*1 Test Circuit for Switching Time



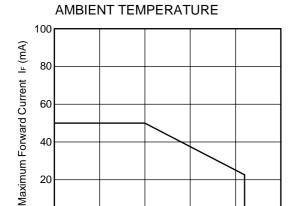


0

-25

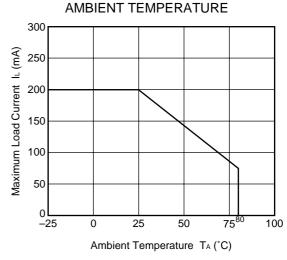
MAXIMUM LOAD CURRENT vs.

#### TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

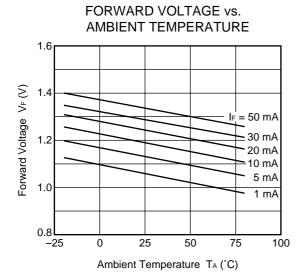


MAXIMUM FORWARD CURRENT vs.

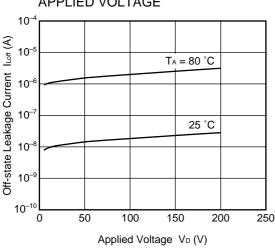
Ambient Temperature TA (°C)



**OUTPUT CAPACITANCE vs.** 



OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE



APPLIED VOLTAGE 250 f = 1 MHzOutput Capacitance Cout (pF)

60 Applied Voltage V<sub>D</sub> (V)

80

100

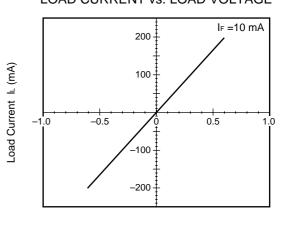
120

20

40

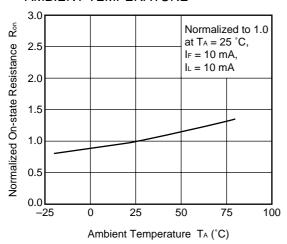
0

#### LOAD CURRENT vs. LOAD VOLTAGE

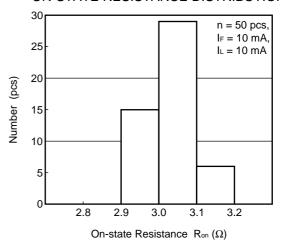


Load Voltage V<sub>L</sub> (V)

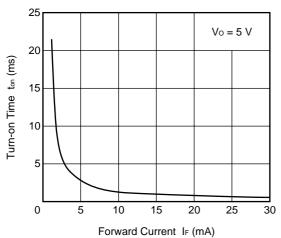
### NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



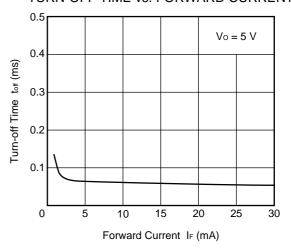
#### **ON-STATE RESISTANCE DISTRIBUTION**



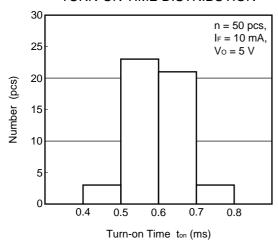
#### TURN-ON TIME vs. FORWARD CURRENT



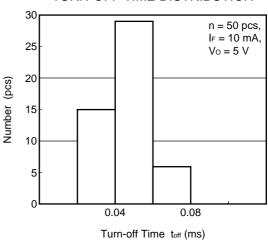
#### TURN-OFF TIME vs. FORWARD CURRENT



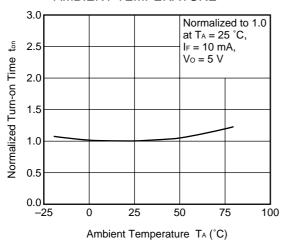
#### TURN-ON TIME DISTRIBUTION



#### TURN-OFF TIME DISTRIBUTION

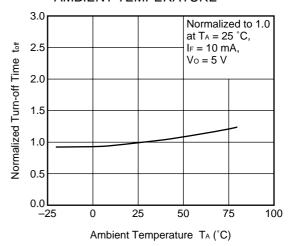


### NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

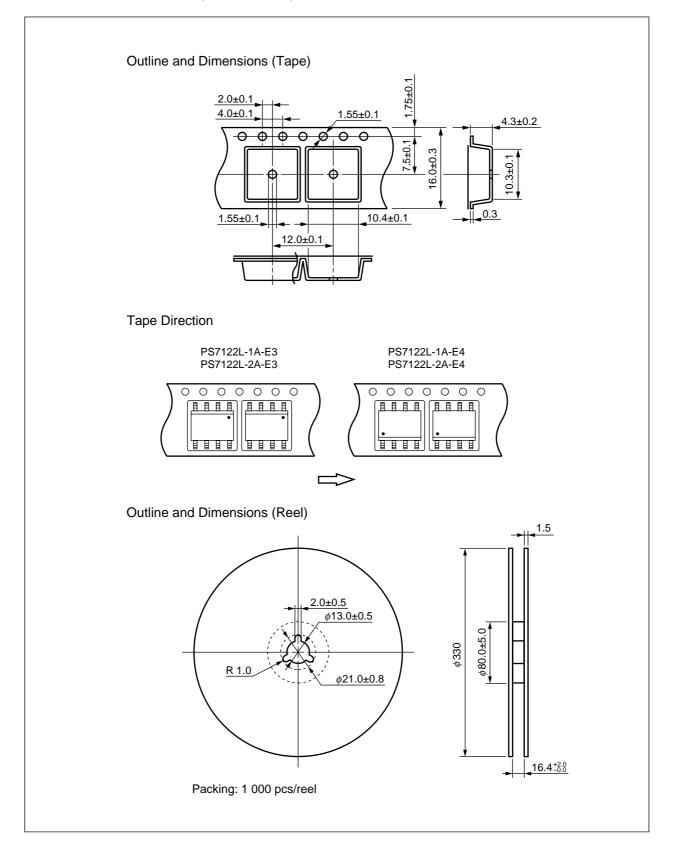


**Remark** The graphs indicate nominal characteristics.

## NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



#### \* TAPING SPECIFICATIONS (in millimeters)



#### RECOMMENDED SOLDERING CONDITIONS

#### (1) Infrared reflow soldering

• Peak reflow temperature 235 °C (package surface temperature)

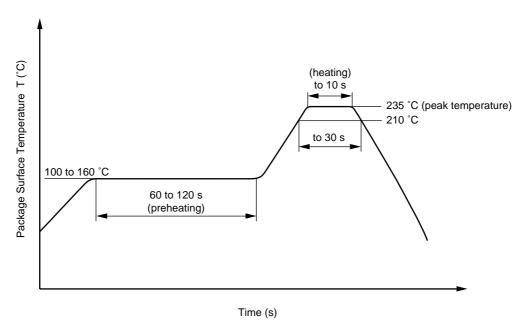
• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Two

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt % is recommended.)

#### Recommended Temperature Profile of Infrared Reflow



#### (2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt % is recommended.)

#### (3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

#### **CAUTION**

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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